



DMTH6005LPSQ

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D T _C = +25°C (Note 10)
60V	5.5mΩ @ V _{GS} = 10V	100A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- High Frequency Switching
- Sync. Rectification
- DCDC Converters

60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI[®]

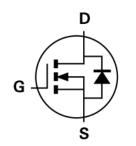
Features

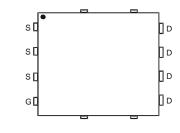
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low R_{DS(ON)} minimizes power losses
- Low Q_g minimizes switching losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: POWERDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)







Internal Schematic

Top View Pin Configuration

Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH6005LPSQ-13	POWERDI [®] 5060-8	2,500 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free.

Notes:

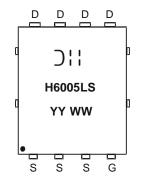
3. Halogen - and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. Automotive products are AEC-Q101 qualified and are PPAP capable. For more information, please refer to

http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



) | | = Manufacturer's Marking H6005LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 15 = 2015) WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	60	V		
Gate-Source Voltage		V _{GSS}	±20	V	
Continuous Drain Current (Note 6)	T _A = +25°C T _A = +70°C	ID	20.6 17.2	A	
Continuous Drain Current (Note 7)	T _C = +25°C (Note 10)	ID	100	А	
	T _C = +100°C		90		
Maximum Continuous Body Diode Forward Current (Note 7)	Is	100	A		
Pulsed Drain Current (10μs pulse, duty cycle = 1%)		I _{DM}	160	A	
Avalanche Current, L=1mH		I _{AS}	14.8	A	
Avalanche Energy, L=1mH		E _{AS}	98	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 6)	T _A = +25°C	PD	3.2	W
Thermal Resistance, Junction to Ambient (Note 6)		R _{θJA}	47	°C/W
Total Power Dissipation (Note 7)	T _C = +25°C	PD	150	W
Thermal Resistance, Junction to Case (Note 7)		R _{0JC}	1	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)						·	
Gate Threshold Voltage	V _{GS(TH)}	1	-	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
		-	4.4	5.5		$V_{GS} = 10V, I_D = 50A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	5.7	7.2	mΩ	$V_{GS} = 6V, I_D = 20A$	
	-(-)	-	7.7	10		V _{GS} = 4.5V, I _D = 12.5A	
Diode Forward Voltage	V _{SD}	-	0.9	-	V	$V_{GS} = 0V, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	-	2962	-			
Output Capacitance	Coss	-	965.2	-	pF	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	-	59.8	-			
Gate Resistance	Rq	-	0.66	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qq	-	47.1	-		V _{DD} = 30V, I _D = 50A	
Total Gate Charge (V _{GS} = 4.5V)	Qq	-	23.1	-	-0		
Gate-Source Charge	Q _{qs}	-	10.2	-	nC		
Gate-Drain Charge	Q _{gd}	-	12.5	-			
Turn-On Delay Time	t _{D(ON)}	-	8.3	-		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 30A, R_G = 3.3\Omega$	
Turn-On Rise Time	t _R	-	9.4	-			
Turn-Off Delay Time	t _{D(OFF)}	-	22	-	ns		
Turn-Off Fall Time	tF	-	8.9	-			
Body Diode Reverse Recovery Time	t _{RR}	-	40.4	-	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	-	49.7	-	nC	I _F = 30A, di/dt = 100A/μs	

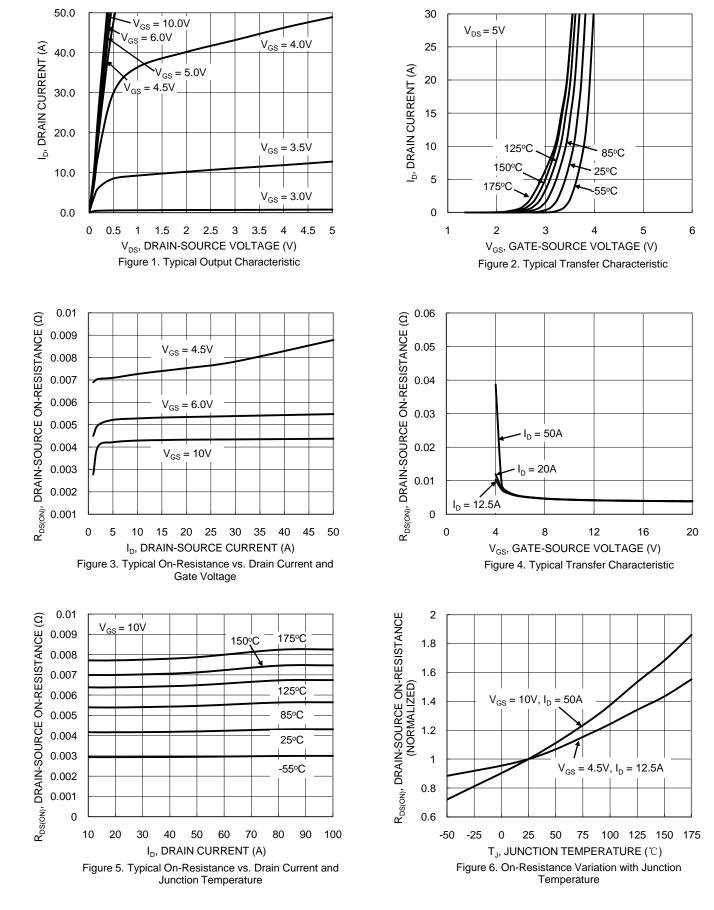
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.
10. Package limited.

Notes:

POWERDI is a registered trademark of Diodes Incorporated. DMTH6005LPSQ Document number: DS38359 Rev.1 - 2



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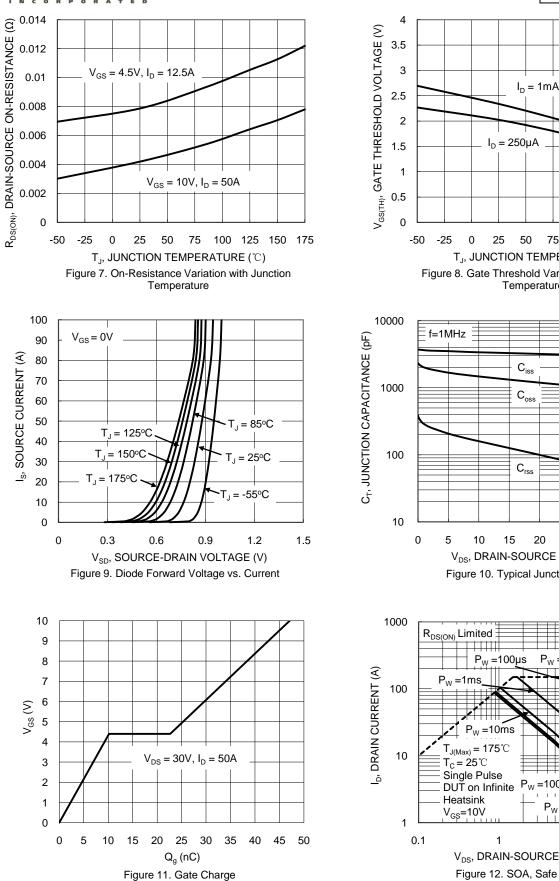


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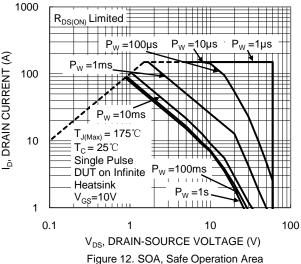
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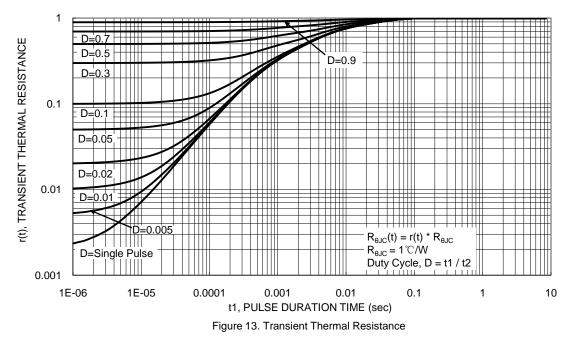


50 75 100 125 150 175 T., JUNCTION TEMPERATURE (°C) Figure 8. Gate Threshold Variation vs. Junction Temperature $\mathbf{C}_{\mathrm{iss}}$ C_{oss} Crss 20 25 30 40 35 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 10. Typical Junction Capacitance



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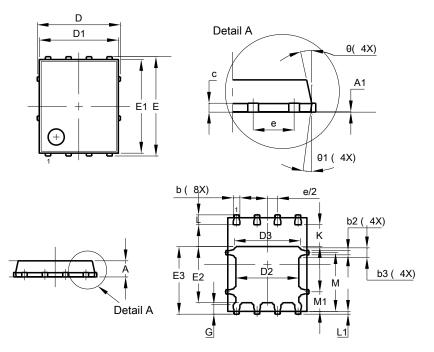






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



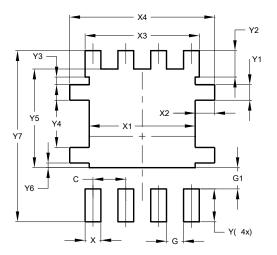
	POWERDI [®] 5060-8					
Dim	Min	Тур				
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
E	(6.15 BSC				
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
θ	10º	12º	11º			
θ1	6°	8º	7°			
Al	All Dimensions in mm					

POWERDI[®]5060-8

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

POWERDI[®]5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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